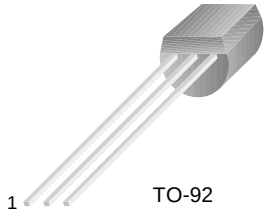
FAIRCHILD
SEMICONDUCTOR®

KSD227

Low Frequency Power Amplifier

- Complement to KSA642
- Collector Power Dissipation : P_C=400mW



TO-92

1. Emitter 2. Base 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	30	V
V_{CEO}	Collector-Emitter Voltage	25	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current	300	mA
P_C	Collector Power Dissipation	400	mW
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	I_C=100μA, I_E=0	30			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C=10mA, I_B=0	25			V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_E=10μA, I_C=0	5			V
I_{CBO}	Collector Cut-off Current	V_{CB}=25V, I_E=0			0.1	μA
I_{EBO}	Emitter Cut-off Current	V_{EB}=3V, I_C=0			0.1	μA
h_{FE}	DC Current Gain	V_{CE}=1V, I_C=50mA	70		400	
V_{CE} (sat)	Collector-Emitter Saturation Voltage	I_C=300mA, I_B=30mA		0.14	0.4	V

h_{FE} Classification

Classification	O	Y	G
h_{FE}	70 ~ 140	120 ~ 240	200 ~ 400

Typical Characteristics

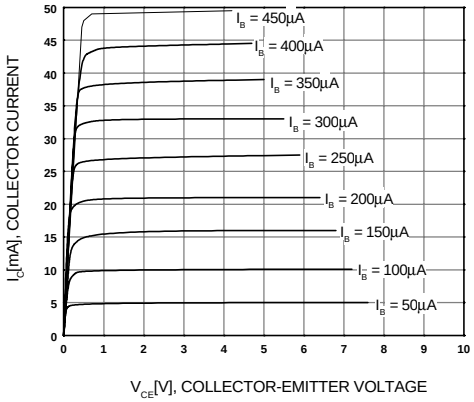


Figure 1. Static Characteristic

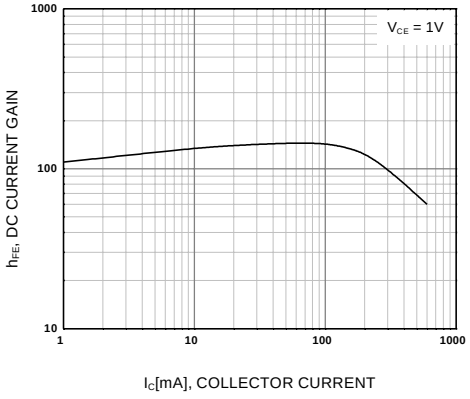


Figure 2. DC current Gain

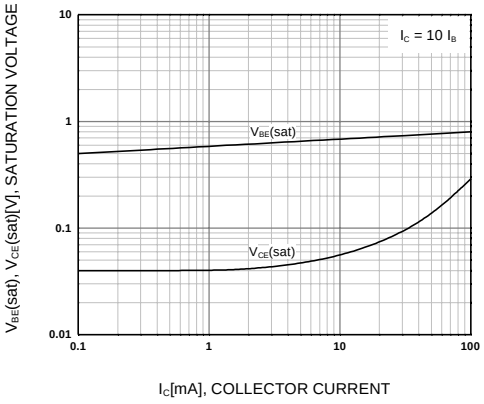


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

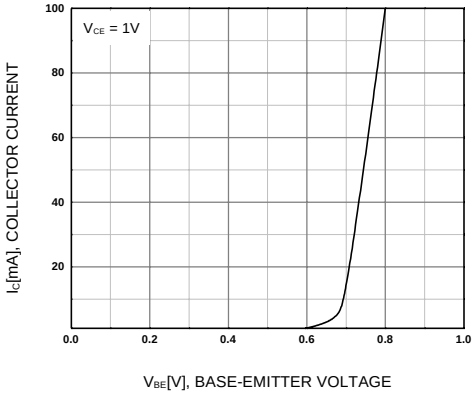


Figure 4. Base-Emitter On Voltage

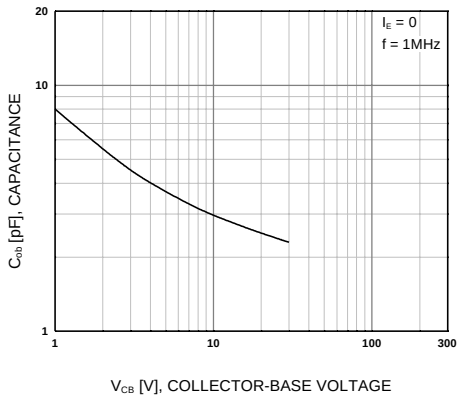


Figure 5. Collector Output Capacitance

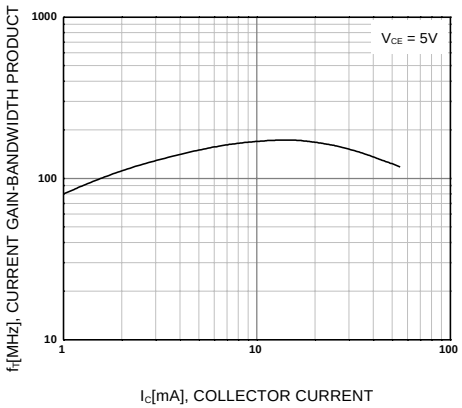


Figure 6. Current Gain Bandwidth Product

Package Dimensions

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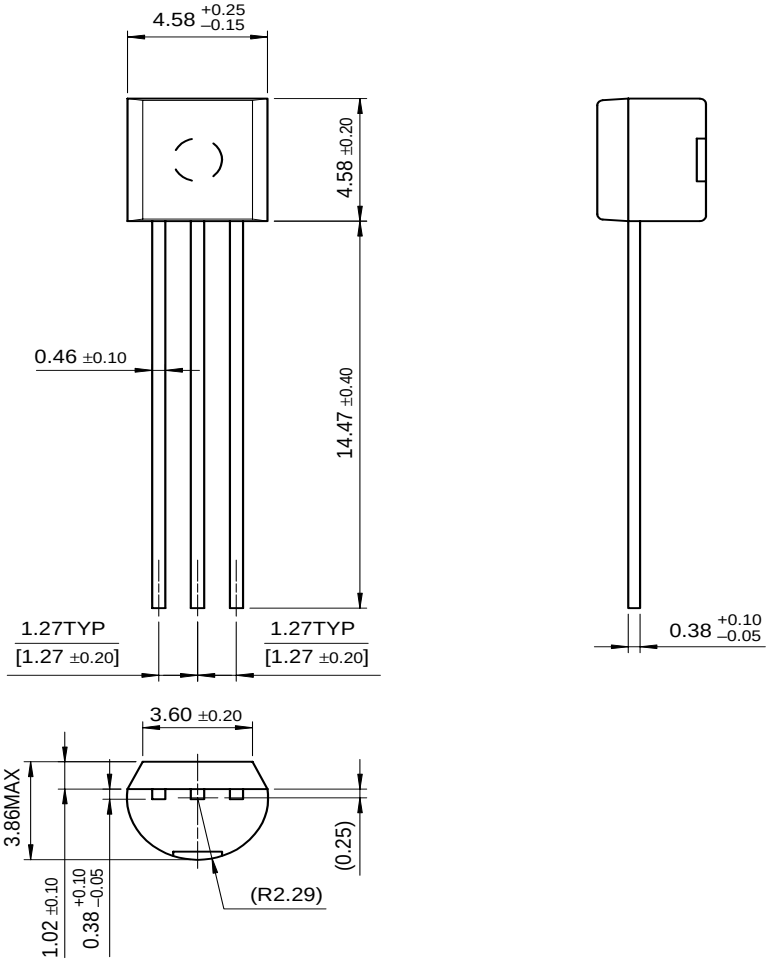

Dimensions in Millimeters

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Bottomless™	FAST®	LittleFET™	Power247™	SuperSOT™-3
CoolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E^2CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I^2C™	OCX™	RapidConfigure™	UHC™
Across the board. Around the world.™		OCXPro™	RapidConnect™	UltraFET®
The Power Franchise™		OPTOLOGIC®	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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